

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	8173	((438/39) or (438/40) or (438/41) or (438/47) or (438/151) or (438/164) or (438/197) or (438/191) or (438/299) or (438/301) or (438/302) or (438/312) or (438/339) or (438/341) or (438/343) or (438/364) or (438/479) or (438/713)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/17 00:19
L2	4	("20010036731") or ("20020003256") or ("20030025126") or ("20030057486").PN.	US-PGPUB	OR	OFF	2005/04/17 00:20
L3	291	1 and (mesa near2 structure\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/17 00:24
L4	29	3 and (soi or (silicon near2 insulator))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/17 00:24
S1	7682	((438/39) or (438/40) or (438/41) or (438/47) or (438/151) or (438/164) or (438/197) or (438/191) or (438/299) or (438/301) or (438/302) or (438/312) or (438/339) or (438/341) or (438/343) or (438/364) or (438/479) or (438/713)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/17 00:19
S2	274	S1 and (mesa near2 structure\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/17 00:24
S3	27	S2 and (soi or (silicon near2 insulator))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/17 00:24
S4	1	("5905286").PN.	USPAT	OR	OFF	2004/11/12 23:48

S5	88	(soi or (silicon near2 insulator)) same (mesa near2 structure\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/13 00:03
S6	77	S5 not S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/13 00:04
S7	363	(mesa near2 structure\$1) same (gate or (gate adj electrode))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/14 08:31
S8	75	S7 and (soi or (silicon near2 insulator))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/14 08:32
S9	12	("4412868" "4740826" "4788158" "4824797" "4942445" "4951102" "4992838" "4994871" "5072276" "5164325" "5240865" "5378914").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/14 08:46
S10	36	("5443992").URPN.	USPAT	OR	OFF	2004/11/14 08:47
S11	0	("2004/0197977").URPN.	USPAT	OR	OFF	2004/11/14 08:52
S12	7934	((438/39) or (438/40) or (438/41) or (438/47) or (438/151) or (438/164) or (438/197) or (438/191) or (438/299) or (438/301) or (438/302) or (438/312) or (438/339) or (438/341) or (438/343) or (438/364) or (438/479) or (438/713)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/05 21:36
S13	314	S12 and (mesa near2 (structure\$1 or formation\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 21:36

S14	33	S13 and (soi or (silicon near2 insulator))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 21:37
S15	2	(("5612230") or ("6207511") or ("2002177263")):PN.	US-PGPUB; USPAT	OR	OFF	2005/02/05 21:05
S16	8273	((438/39) or (438/40) or (438/41) or (438/47) or (438/151) or (438/164) or (438/197) or (438/191) or (438/299) or (438/300) or (438/301) or (438/302) or (438/312) or (438/339) or (438/341) or (438/343) or (438/364) or (438/479) or (438/713)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/05 21:36
S17	317	S16 and (mesa near2 (structure\$1 or formation\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 21:36
S18	36	S17 and (soi or (silicon near2 insulator))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 21:37